

Mid-Infrared (MIR) Photodiode Series with glass cover

Lms36PD-03-CG series

Device parameters	Symbol	Value	Units
PD chip sensitive area size	d	0.3	mm
Operating temperature	T _{opr}	0+50	°C
Storage temperature	T_{stg}	0+40	°C
Soldering temperature (time < 3 seconds, 3 mm from the case)	T _{sol}	+180	°C
Reverse voltage	V _r	0.1	V

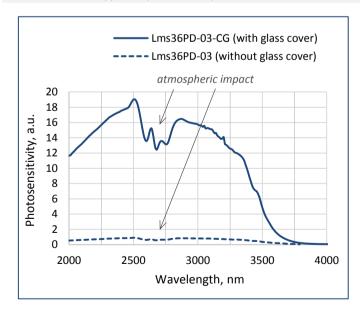


All parameters refer to photodiode operation at ambient temperature 25°C unless otherwise stated.

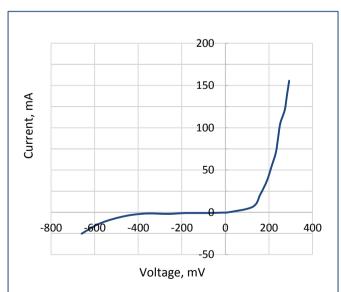
Photodiode parameters	Conditions	Symbol	Value	Units			
Cut-off wavelength (at 10% level) ¹	-	λ_{cut}	3.7 - 3.8	μm			
Max. sensitivity range (at 80% level) ¹	-	λ_{p}	2.4 - 3.1	μm			
Dark current (typical/ maximal) ²	$V_r = 0.1 V$	l _d	typ 80 / max 300	μΑ			
Shunt resistance (minimal/ typical) ²	$V_r = 10 \text{ mV}$	R_{sh}	min 0.4 / typ 1.5	kΩ			
Capacitance (typical/ maximal) ¹	$V_r = 10 \text{ mV}$	С	typ 250 / max 300	pF			
Noise equivalent power (typical/ maximal) ^{2, 3}	λ = 3.3 μm	NEP	typ 2.5*10 ⁻¹³ / max 9.6*10 ⁻¹³	W/Hz ^{1/2}			
Detectivity (minimal/ typical) ^{2, 3}	λ = 3.3 μm	D*	min 3.2*10 ¹⁰ / typ 1.2*10 ¹¹	cm [·] Hz ^{1/2} ·W ⁻¹			

¹ Parameter tested for representative sampling.

Typical spectral response



Typical current-voltage characteristic



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² Parameter tested for each device.

³ Parameters are calculated using photosensitivity value [A/W] obtained for the same photodiode prior to glass covering multiplied by the coefficient equal to the ratio of response of PD with and without glass covering (measured at $\lambda = 3.3 \mu m$).



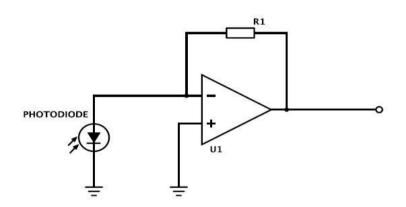
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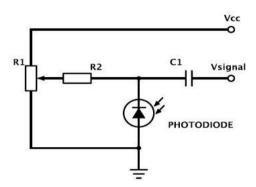
Packages	Model
TO-18 with glass cover	Lms36PD-03-CG
PD with a built-in preamplifier; TO-18 with glass cover and a parabolic reflector without a window in an aluminium tube	Lms36PD-03-CG-R-PA

Recommended modes of PD operation

PD used as a current source (photovoltaic mode)

PD used in a photoconductive mode (under reverse bias)





We recommend using **photovoltaic mode**, when PD is used under no reverse bias. Use photoconductive mode (mode with reverse bias) with caution.

IMPORTANT CAUTIONS:

- check your connection circuit before turning on the PD;
- mind the PD polarity: PD anode is marked with a RED dot;
- do not connect the PD to the multimeter;
- do not touch the glass covering and do not apply any force to it;
- observe the allowable operating temperature range, exceeding this eange may cause irreparable damage of the glass cover

Related products:

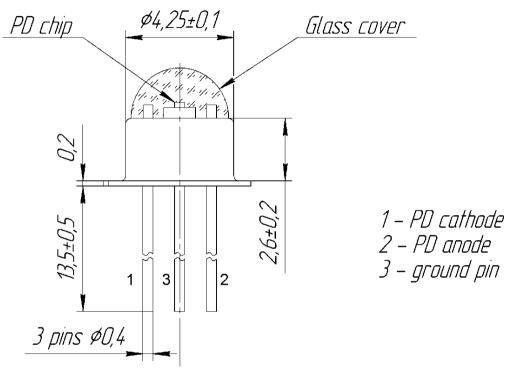
- Light emitting diodes (LEDs) sources of IR radiation;
- PAb preamplifier amplifies photocurrent generated by a PD and converts it into a voltage signal;
- **SDM synchronous detector** enables synchronous operation of a PD coupled with a preamplifier and an LED coupled with a driver; performs convertion of an output PD preamplifier signal into DC voltage signal.

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Technical Drawings

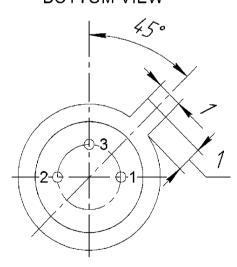
Lms36PD-03-CG



TOP VIEW

PD chip \$2,5±0,1

BOTTOM VIEW



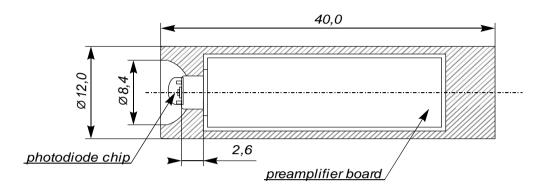
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Mid-Infrared (MIR) Photodiode Series with glass cover

Technical Drawings

Lms36PD-03-CG-R-PA



Power input voltage: +5 V, stabilized;

Connections:

The output of PD with a built-in preamplifier has four wires:

- "+" power input (to the "+5V" of the power output terminal block of the SDM synchronous detector);
- "ground" power input (to the "0V" of the power output terminal block of the SDM synchronous detector);
- "ground" output photodiode signal (to the "0V" of the signal input terminal block of the SDM synchronous detector);
- "+" output photodiode signal (to the "IN" of the signal input terminal block of the SDM synchronous detector).

For the proper connection mind the colours of the wires pointed in the technical data provided with the photodiode.